

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and

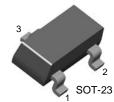
February 2008



MMBT5770 NPN RF Transistor

• This device is designed for use as RF amplifiers, oscillators and multipliers with collector currents in the 1.0 mA to 30 mA range.

• Sourced from process 43.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	30	V	
V _{CEO}	Collector-Emitter Voltage	15	V	
V _{EBO}	Emitter-Base Voltage	4.5	V	
I _C Collector Current - Continuous		10	mA	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

Thermal Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	225 1.8	mW mW/°C
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	556	°C/W

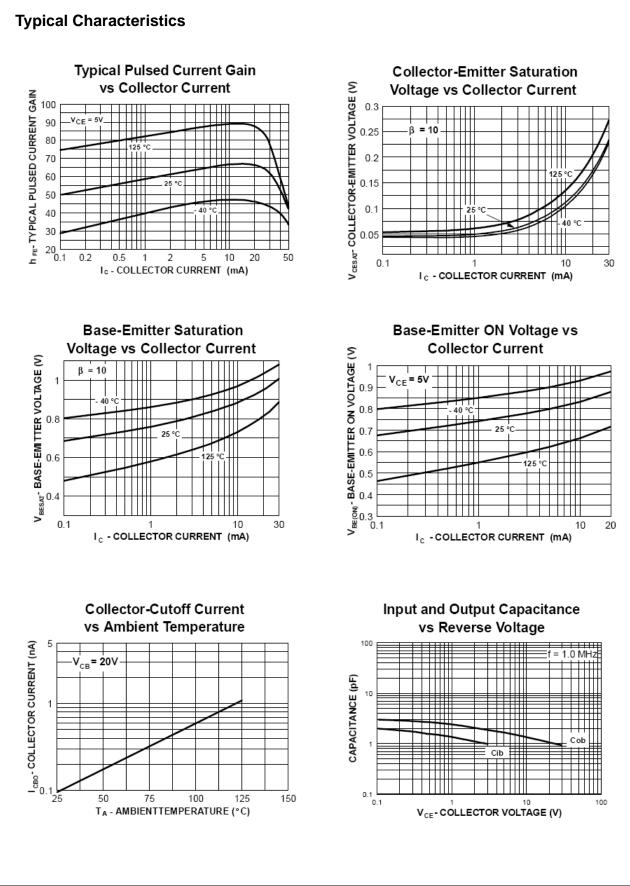
* Device mounted on FR-4PCB 1.6" \times 1.6" \times 0.06".

Electrical Characteristics $T_a=25$ °C unless otherwise noted

Parameter	Test Condition	Min.	Max.	Units
teristics	•			
Collector-Base Breakdown Voltage	$Ic = 1.0 \ \mu A, \ Ie = 0$	30		V
Collector-Emitter Sustaining Voltage*	Ic = 3.0 mA, I _B = 0	15		V
Emitter-Base Breakdown Voltage	$I_E = 10 \ \mu A, \ I_C = 0$	3		V
Collector-Cutoff Current	V _{CB} = 15 V, I _E = 0		50	nA
teristics *			•	•
DC Current Gain	V _{CE} = 1.0V, I _C = 3.0mA	30		
Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 1.0mA		0.4	V
Base-Emitter Saturation Voltage	I _C = 10mA, I _B = 1.0mA		1.0	V
al Characteristics	ł		•	•
Current Gain Bandwidth Product	I _C = 4.0mA, V _{CE} = 10V, f = 100MHz	600		MHz
	teristics Collector-Base Breakdown Voltage Collector-Emitter Sustaining Voltage* Emitter-Base Breakdown Voltage Collector-Cutoff Current teristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage al Characteristics	teristicsCollector-Base Breakdown VoltageIc = 1.0 μ A, IE = 0Collector-Emitter Sustaining Voltage*Ic = 3.0 mA, IB = 0Emitter-Base Breakdown VoltageIE = 10 μ A, Ic = 0Collector-Cutoff CurrentVCB = 15 V, IE = 0teristics *DC Current GainVCE = 1.0V, IC = 3.0mACollector-Emitter Saturation VoltageIC = 10mA, IB = 1.0mABase-Emitter Saturation VoltageIC = 10mA, IB = 1.0mAal CharacteristicsIC = 10mA, IB = 1.0mA	teristicsCollector-Base Breakdown VoltageIc = 1.0 μ A, IE = 030Collector-Emitter Sustaining Voltage*Ic = 3.0 mA, IB = 015Emitter-Base Breakdown VoltageIE = 10 μ A, Ic = 03Collector-Cutoff CurrentVCB = 15 V, IE = 03Collector-Cutoff CurrentVCE = 1.0V, IC = 3.0 mA30Collector-Emitter Saturation VoltageIC = 10 mA, IB = 1.0 mA30Collector-Emitter Saturation VoltageIC = 10 mA, IB = 1.0 mA30Collector-Emitter Saturation VoltageIC = 10 mA, IB = 1.0 mA30Collector-Emitter Saturation VoltageIC = 10 mA, IB = 1.0 mA30	teristicsCollector-Base Breakdown VoltageIc = 1.0 μ A, IE = 030Collector-Emitter Sustaining Voltage*Ic = 3.0 mA, IB = 015Emitter-Base Breakdown VoltageIE = 10 μ A, Ic = 03Collector-Cutoff CurrentVcB = 15 V, IE = 050teristics *DC Current GainV _{CE} = 1.0V, I _C = 3.0mA30Collector-Emitter Saturation VoltageI _C = 10mA, I _B = 1.0mA0.4Base-Emitter Saturation VoltageI _C = 10mA, I _B = 1.0mA1.0al Characteristics

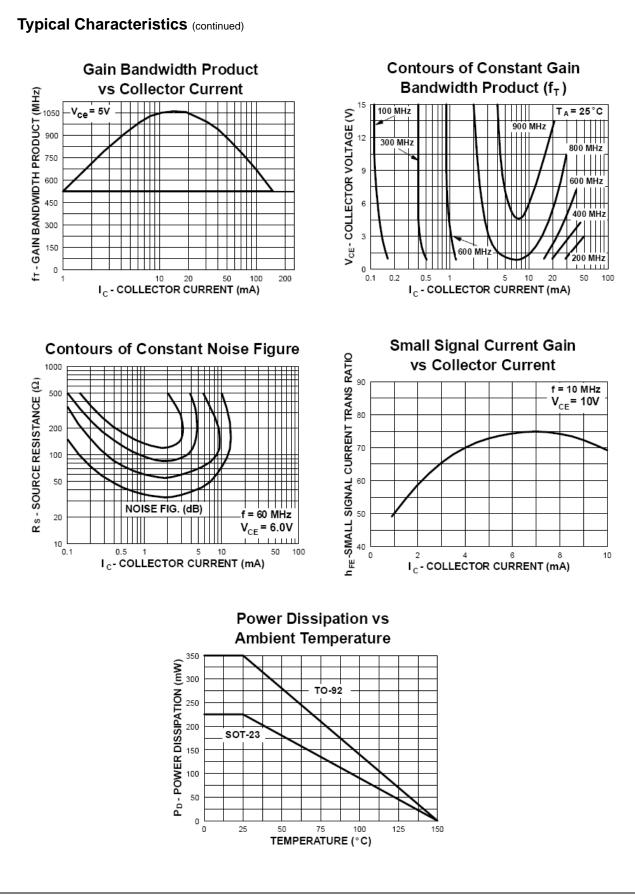
* Pulse Test: Pulse Width ${\leq}300\mu s,$ Duty Cycle ${\leq}2\%$

© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0



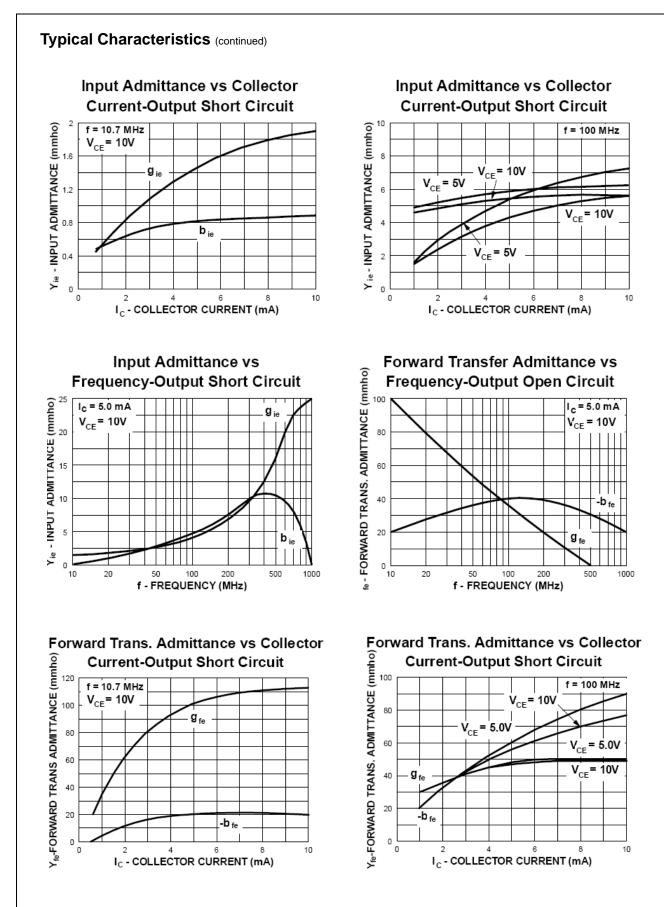
© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0

MMBT5770 — NPN RF Transistor

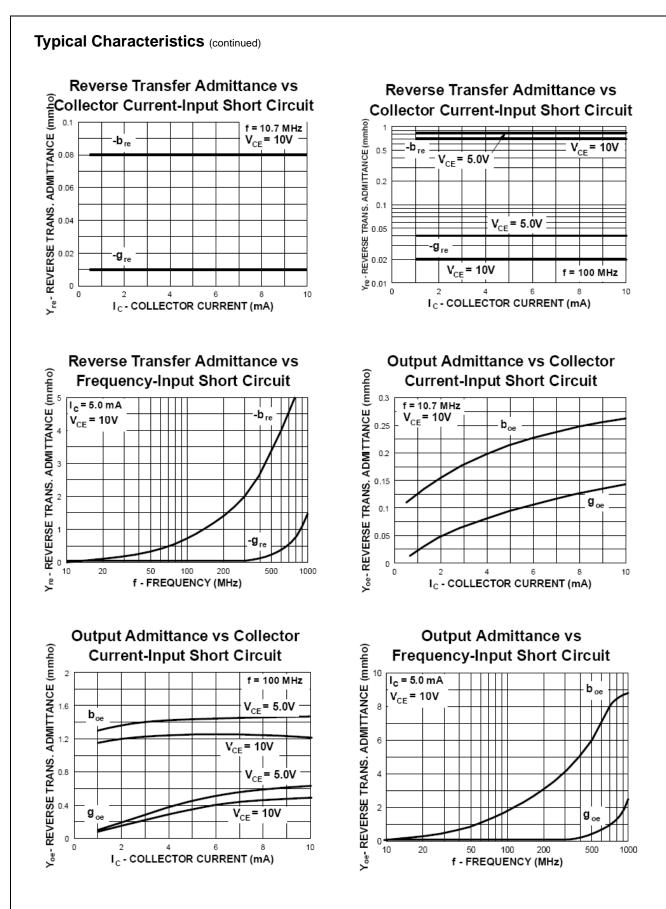


© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0 MMBT5770 — NPN RF Transistor





© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0



© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0



SEMICONDUCTOR

TRADEMARKS

The following are registered and unregistered trademarks and service marks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

Power247[®]

ACEx® Build it Now™ CorePLUS™ CROSSVOLT™ CTL™ Current Transfer Logic™ EcoSPARK[®] Fairchild® Fairchild Semiconductor® FACT Quiet Series[™] FACT® FAST® FastvCore™ FPS™ FRFET[®] Global Power ResourceSM Green FPS™ Green FPS™ e-Series™ GTO™ i-Lo™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MillerDrive™ Motion-SPM[™] **OPTOLOGIC[®] OPTOPLANAR[®]** R PDP-SPM™ Power220[®]

POWEREDGE[®] Power-SPM[™] PowerTrench[®] Programmable Active Droop[™] QFET[®] QS[™] QT Optoelectronics[™] Quiet Series[™] RapidConfigure[™] SMART START[™] SMART START[™] SPM[®] STEALTH[™] SuperFET[™] SuperSOT[™]-3 SuperSOT[™]-6 SuperSOT[™]-8 SyncFET[™] The Power Franchise[®]

TinyBoost™ TinyBuck™ TinyLogic[®] TINYOPTO™

TinyLogic® TINYOPTO™ TinyPower™ TinyWire™ µSerDes™ UHC® UniFET™ VCX™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Datasheet Identification	Product Status	Definition This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.	
Advance Information	Formative or In Design		
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be pub- lished at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.	
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserve the right to make changes at any time without notice to improve design.	
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontin- ued by Fairchild semiconductor. The datasheet is printed for reference infor- mation only.	

© 2007 Fairchild Semiconductor Corporation MMBT5770 Rev. 1.0.0

PRODUCT STATUS DEFINITIONS

www.fairchildsemi.com

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death a

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Downloaded from Arrow.com.